NSN 5961-01-006-1335

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-006-1335 **Inclosure Material:** Metal **Overall Length:** Between 5.282 inches and 5.592 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-30 **Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 1.031 inches and 1.063 inches **Thread Size:** 0.500 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 repetitive peak reverse voltage and 300.0 nonrepetitive peak reverse voltage **Current Rating Per Characteristic:** 16.00 amperes forward current, average minor and 150.00 amperes collector current, dc and 3000.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 insulated wire lead w/terminal lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure:** Demilitarization: